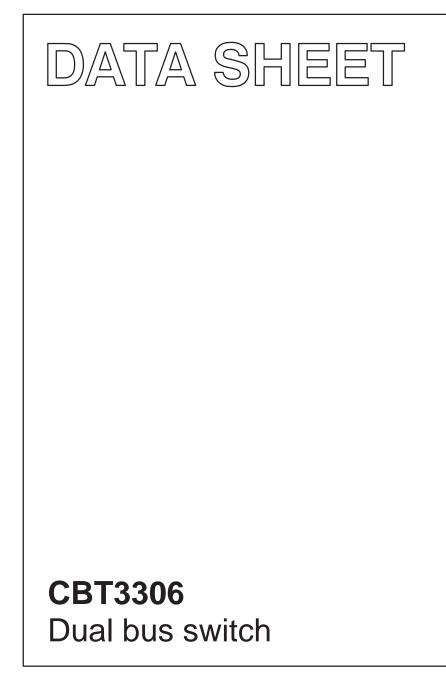
INTEGRATED CIRCUITS



Product data

2001 Nov 08

File under Integrated Circuits — ICL03







Dual bus switch

CBT3306

FEATURES

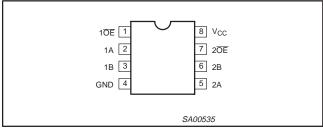
- 5 Ω switch connection between two ports
- TTL-compatible input levels
- Package options include plastic small outline (SO) and thin shrink small outline (TSSOP)
- Latch-up protection exceeds 100 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114 and 1000 V CDM per JESD22-C101

DESCRIPTION

The CBT3306 Dual FET Bus Switch features independent line switches. Each switch is disabled with the associated Output Enable $(\overline{\text{OE}})$ input is high.

The CBT3306 is characterized for operation from -40 to +85 °C.

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 7	1 <u>0E</u> , 2 <u>0E</u>	Output enable
2, 5	1A, 2A	A port inputs
3, 6	1B, 2B	B port outputs
4	GND	Ground (0 V)
8	V _{CC}	Positive supply voltage

QUICK REFERENCE DATA

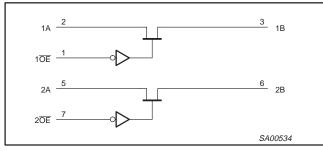
SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay A to B or B to A	C_L = 50 pF; V_{CC} = +5.0 V ±0.5 V	0.25 (MAX)	ns
C _{IO(OFF)}	Pin capacitance (OFF state)	$V_O = 3 V \text{ or } 0; \overline{OE} = V_{CC}$	6.45	pF
I _{CC}	Quiescent supply current	V_{CC} = 5.5 V; I_{O} = 0, V_{I} = V_{CC} or GND	3	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
8-pin plastic SO	–40 to 85 °C	CBT3306D	SOT96-1
8-pin plastic TSSOP	–40 to 85 °C	CBT3306PW	SOT530-1

Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

LOGIC DIAGRAM (positive logic)



FUNCTION TABLE

INPUT	FUNCTION	
ŌE	FUNCTION	
L	A port = B port	
Н	Disconnect	

CBT3306

ABSOLUTE MAXIMUM RATINGS¹

 $T_{amb} = -40$ to +85 °C, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
VI	DC input voltage ²		-0.5 to +7.0	V
I _{OUT}	DC output current		128	mA
I _{IK}	Diode current	V _{I/O} < 0	-50	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. The package thermal impedance is calculated in accordance with JESD 51. 2.

3.

RECOMMENDED OPERATING CONDITIONS¹

SYMBOL	PARAMETER	LIM	UNIT	
	PARAMETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
VIH	High-level input voltage	2.0	—	V
VIL	Low-level Input voltage	—	0.8	V
T _{amb}	Operating free-air temperature range -40 +85			°C

NOTE:

1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS

 $T_{amb} = -40$ to +85 °C, unless otherwise specified.

				UNIT		
SYMBOL	PARAMETER	TEST CONDITIONS	$T_{amb} = -40$ to +85 °C			
			MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$	_	_	-1.2	V
Ц	Input leakage current	V_{CC} = 5.5 V; V_{I} = GND or 5.5 V	_	—	±1	μΑ
I _{CC}	Quiescent supply current	V_{CC} = 5.5 V; I_O = 0, V_I = V_{CC} or GND	_	—	3	μΑ
VP	Output high pass voltage	$V_I = V_{CC} = 5.0 \text{ V}; I_O = -100 \mu\text{A}$	3.4	3.6	3.9	V
ΔI _{CC}	Additional supply current per input pin ²	V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V_{CC} or GND	_	_	2.5	mA
Cl	Control pin capacitance	V _I = 3 V or 0	—	3.15		pF
C _{IO(OFF)}	Port off capacitance	$V_{O} = 3 V \text{ or } 0; \overline{OE} = V_{CC}$	_	6.45	_	pF
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 64 \text{ mA}$	_	3.4	5	Ω
r _{on} ³	On-resistance	$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 30 \text{ mA}$	_	3.4	5	Ω
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 2.4 \text{ V}; \text{ I}_{I} = 15 \text{ mA}$	_	6.8	7.5	Ω

NOTES:

1. All typical values are at $V_{CC} = 5 \text{ V}$, $T_{amb} = 25 \text{ °C}$. 2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND

3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

CBT3306

AC CHARACTERISTICS

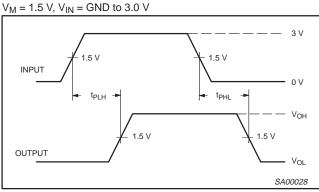
 $T_{amb} = -40$ to +85 °C; $C_L = 50$ pF

				LIMITS		
SYMBOL	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = +5.0	0 V ±0.5 V	UNIT
			(001101)	MIN	МАХ	
t _{pd}	Propagation delay ¹	A or B	B or A	_	0.25	ns
t _{en}	Output enable time to High and Low level	ŌĒ	A or B	1.8	5	ns
t _{dis}	Output disable time from High and Low level	ŌĒ	A or B	1	5	ns

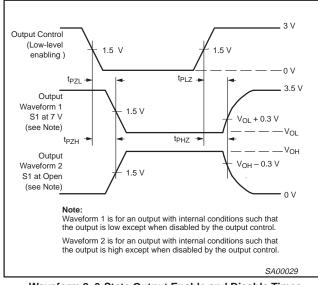
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

AC WAVEFORMS



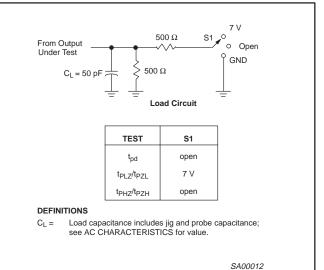




Waveform 2. 3-State Output Enable and Disable Times NOTES:

- 1. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- 2. t_{PZL} and t_{PZH} are the same as t_{en} .
- 3. t_{PLH} and t_{PHL} are the same as t_{pd} .

TEST CIRCUIT AND WAVEFORMS



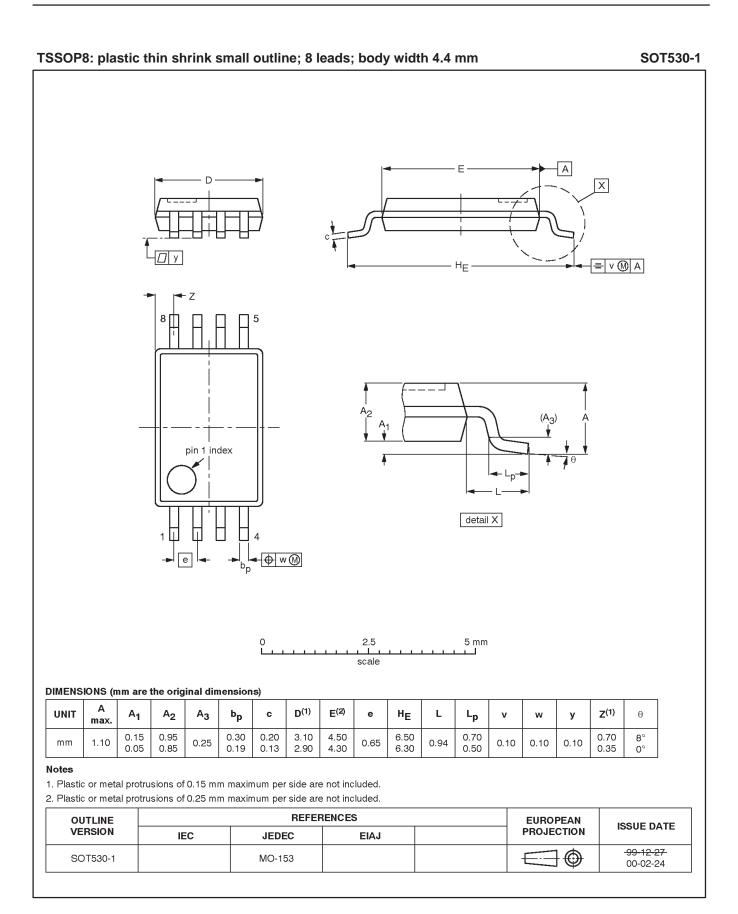
NOTES:

- 1. All input pulses are supplied by generators having the following
- characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns. 2. The outputs are measured one at a time with one transition per measurement.

Dual bus switch

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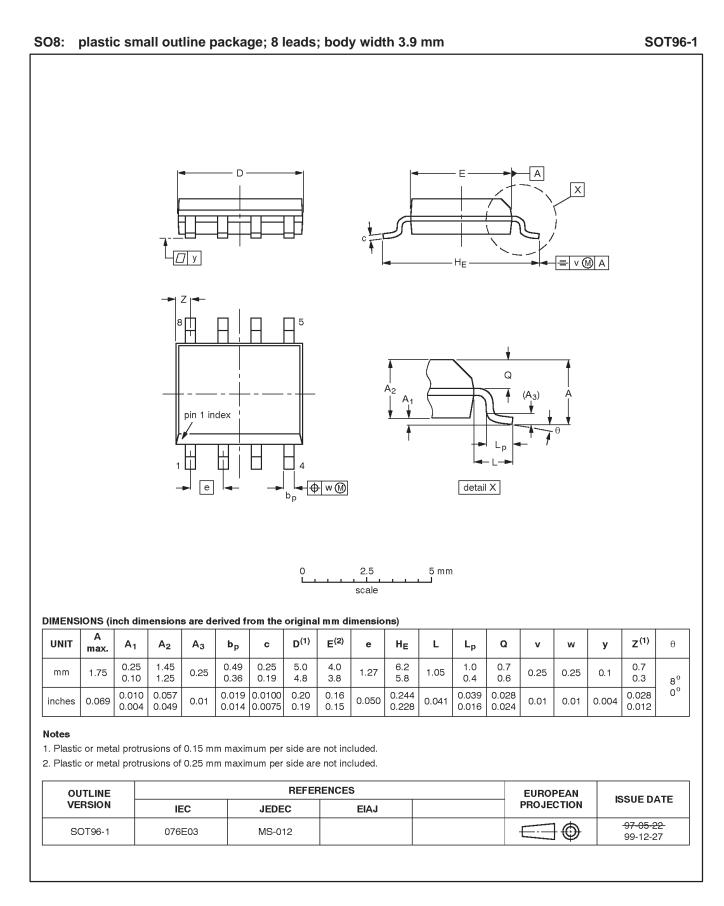
Product data



Dual bus switch

Product data

CBT3306



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NOTES

Product data

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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